NSN 5961-01-062-5743



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-062-5743 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.640 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud Thread Size: 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 breakdown voltage, collector-to-base, emitter open and 33.0 breakdown voltage, collector-to-emitter, base open and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 250.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Ceramic case contains beryllium oxide - handle and dispose iaw hazmat procedures; junction pattern arrangement: npn **Precious Material And Location:** Chip metallization and internal @wires gold **Precious Material:** Gold **Test Data Document:** 13499-352-1059 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: